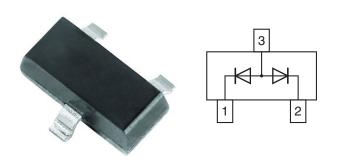


Vishay Semiconductors

Small Signal Switching Diode, Dual



FEATURES

- Silicon epitaxial planar diode
- · Fast switching dual diode with common anode
- AEC-Q101 qualified available
- Base P/N-E3 RoHS-compliant, commercial grade



- Base P/N-HE3 RoHS-compliant, AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

DESIGN SUPPORT TOOLS click logo to get started



MECHANICAL DATA

Case: SOT-23

Weight: approx. 8.8 mg
Packaging codes / options:

18/10K per 13" reel (8 mm tape), 10K/box 08/3K per 7" reel (8 mm tape), 15K/box

PARTS TABLE					
PART	ORDERING CODE	CIRCUIT CONFIGURATION	TYPE MARKING	REMARKS	
BAW56	BAW56-E3-08 or BAW56-E3-18	Common anodo	JD	Tape and reel	
	BAW56-HE3-08 or BAW56-HE3-18	Common anode	JD		

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Repetitive peak reverse voltage = working peak reverse voltage = DC blocking voltage		$V_R = V_{RRM}$	70	V	
Forward continuous current		I _F	250	mA	
	t _p = 1 µs	I _{FSM}	2	Α	
Non repetitive peak forward current	$t_p = 1 \text{ ms}$	I _{FSM}	1	Α	
	t _p = 1 s	I _{FSM}	0.5	Α	
Power dissipation (1)		P _{tot}	350	mW	

THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Thermal resistance junction to ambient air		R _{thJA}	430	K/W	
Junction temperature		T _j	150	°C	
Storage temperature range		T _{stg}	-65 to +150	°C	
Operating temperature range		T _{op}	-55 to +150	°C	

Note

⁽¹⁾ Device on fiberglass substrate, see layout



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ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
	I _F = 1 mA	V_{F}			0.715	>
Forward voltage	I _F = 10 mA	V _F			0.855	V
Forward voltage	I _F = 50 mA	V _F			1	V
	I _F = 150 mA	V _F			1.25	V
	V _R = 70 V	I _R			2500	nA
Reverse current	V _R = 70 V, T _j = 150 °C	I _R			100	μA
	V _R = 25 V, T _j = 150 °C	I _R			30	μA
Diode capacitance	$V_F = V_R = 0 V$, $f = 1 MHz$	C _D			2	pF
Reverse recovery time	I_F = 10 mA to i_R = 1 mA, V_R = 6 V, R_L = 100 Ω	t _{rr}			6	ns

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

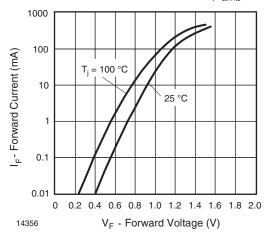


Fig. 1 - Forward Current vs. Forward Voltage

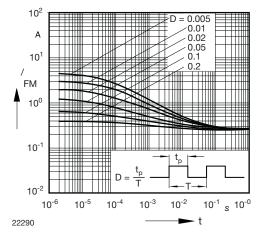
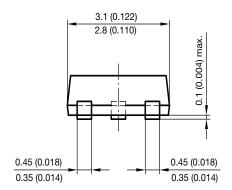


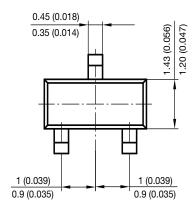
Fig. 2 - Peak Forward Current I_{FM} = f (t_p)



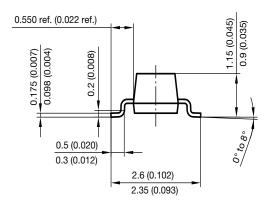
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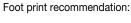
PACKAGE DIMENSIONS in millimeters (inches): SOT-23

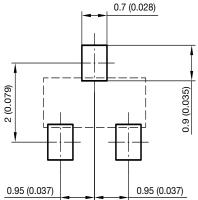




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